## **TEFT4300**

**Vishay Semiconductors** 



DESCRIPTION

950 nm IR emitters.

TEFT4300 is a silicon NPN phototransistor with high radiant sensitivity in black, T-1 plastic package with daylight

blocking filter. Filter bandwitdth is matched with 900 nm to

94 8636-2

### Silicon NPN Phototransistor

### **FEATURES**

- Package type: leaded
- Package form: T-1
- Dimensions (in mm): Ø 3
- · High radiant sensitivity
- Daylight blocking filter matched with 940 nm emitters
- Fast response times
- Angle of half sensitivity:  $\varphi = \pm 30^{\circ}$
- · Package matched with IR emitter series TSUS4300 and TSAL4400
- · Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### Note

Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

#### **APPLICATIONS**

- · Optical switches
- Counters and sorters
- Interrupters
- Encoders
- Position sensors

PRODUCT SUMMARY			
COMPONENT	I <sub>ca</sub> (mA)	φ (deg)	λ <sub>0.5</sub> (nm)
TEFT4300	3.2	± 30	875 to 1000

Note

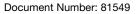
Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
TEFT4300	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1	

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Collector emitter voltage		V <sub>CEO</sub>	70	V
Emitter collector voltage		V <sub>ECO</sub>	5	V
Collector current		Ι <sub>C</sub>	50	mA
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA
Power dissipation	T <sub>amb</sub> ≤ 55 °C	Pv	100	mW
Junction temperature		Tj	100	°C
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C
Soldering temperature	$t \le 3 s$ , 2 mm from case	T <sub>sd</sub>	260	°C
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm <sup>2</sup>	R <sub>thJA</sub>	450	K/W







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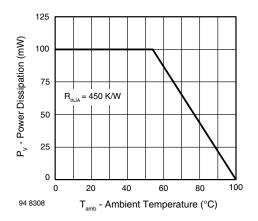


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	I <sub>C</sub> = 1 mA	V <sub>(BR)CEO</sub>	70			V
Collector emitter dark current	$V_{CE} = 20 \text{ V}, \text{ E} = 0$	I <sub>CEO</sub>		1	200	nA
Collector emitter capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz, E = 0	C <sub>CEO</sub>		3		pF
Collector light current	$\begin{array}{l} E_{e} = 1 \ mW/cm^2,  \lambda = 950 \ nm, \\ V_{CE} = 5 \ V \end{array}$	I <sub>ca</sub>	0.8	3.2		mA
Angle of half sensitivity		φ		± 30		deg
Wavelength of peak sensitivity		λρ		925		nm
Range of spectral bandwidth		λ <sub>0.5</sub>		875 to 1000		nm
Collector emitter saturation voltage	$\begin{array}{l} E_{e} = 1 \ mW/cm^2,  \lambda = 950 \ nm, \\ I_{C} = 0.1 \ mA \end{array}$	V <sub>CEsat</sub>			0.3	V
Turn-on time	$V_{S}$ = 5 V, $I_{C}$ = 5 mA, $R_{L}$ = 100 $\Omega$	t <sub>on</sub>		2		μs
Turn-off time	$V_{S}$ = 5 V, $I_{C}$ = 5 mA, $R_{L}$ = 100 $\Omega$	t <sub>off</sub>		2.3		μs
Cut-off frequency	$V_{S}$ = 5 V, $I_{C}$ = 5 mA, $R_{L}$ = 100 $\Omega$	f <sub>c</sub>		180		kHz

### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

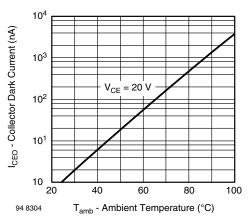


Fig. 1 - Collector Dark Current vs. Ambient Temperature

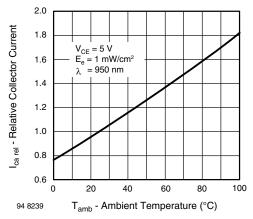
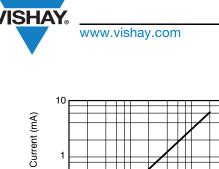


Fig. 2 - Relative Collector Current vs. Ambient Temperature

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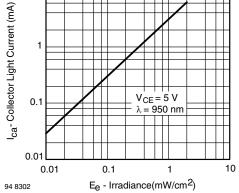


Fig. 3 - Collector Light Current vs. Irradiance

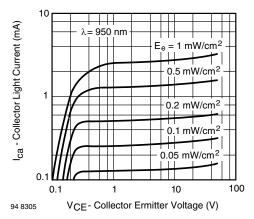


Fig. 4 - Collector Light Current vs. Collector Emitter Voltage

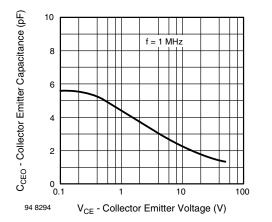


Fig. 5 - Collector Emitter Capacitance vs. Collector Emitter Voltage

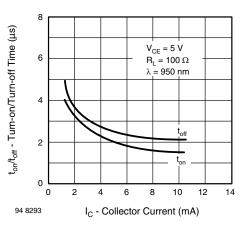


Fig. 6 - Turn-on/Turn-off Time vs. Collector Current

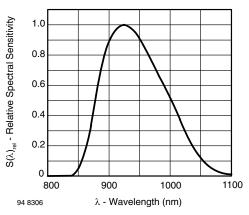


Fig. 7 - Relative Spectral Sensitivity vs. Wavelength

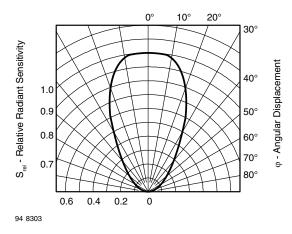


Fig. 8 - Relative Radiant Sensitivity vs. Angular Displacement

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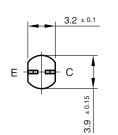
3 For technical questions, contact: <u>detectortechsupport@vishay.com</u>

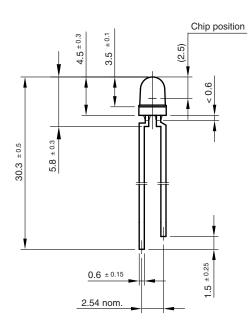
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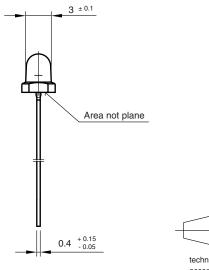


### Vishay Semiconductors

#### **PACKAGE DIMENSIONS** in millimeters









technical drawings according to DIN specifications

Drawing-No.: 6.544-5269.01-4 Issue: 4; 01.12.99 96 12172



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